

FDPF085N10A

N-Channel PowerTrench® MOSFET

100 V, 40 A, 8.5 mΩ

Features

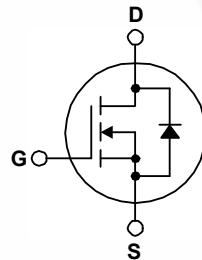
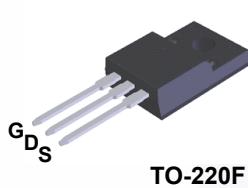
- $R_{DS(on)} = 6.5 \text{ mΩ}$ (Typ.) @ $V_{GS} = 10 \text{ V}$, $I_D = 40 \text{ A}$
- Fast Switching Speed
- Low Gate Charge, $Q_G = 31 \text{ nC}$ (Typ.)
- High Performance Trench Technology for Extremely Low $R_{DS(on)}$
- High Power and Current Handling Capability
- RoHS Compliant

Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench® process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

Applications

- Consumer Appliances
- LED TV
- Synchronous Rectification for ATX / Server / Telecom PSU
- Motor Drives and Uninterruptible Power Supplies
- Micro Solar Inverter



Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter		FDPF085N10A	Unit
V_{DSS}	Drain to Source Voltage		100	V
V_{GSS}	Gate to Source Voltage		± 20	V
I_D	Drain Current	- Continuous ($T_C = 25^\circ\text{C}$)	40	A
		- Continuous ($T_C = 100^\circ\text{C}$)	28	
I_{DM}	Drain Current	- Pulsed	(Note 1)	A
E_{AS}	Single Pulsed Avalanche Energy		(Note 2)	mJ
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	V/ns
P_D	Power Dissipation	($T_C = 25^\circ\text{C}$)	33.3	W
		- Derate Above 25°C	0.22	
T_J, T_{STG}	Operating and Storage Temperature Range		-55 to +175	°C
T_L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300	°C

Thermal Characteristics

Symbol	Parameter	FDPF085N10A	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	4.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDPF085N10A	FDPF085N10A	TO-220F	Tube	N/A	N/A	50 units

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu\text{A}, V_{GS} = 0 \text{ V}$	100	-	-	V
$\Delta \text{BV}_{\text{DSS}} / \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}, \text{Referenced to } 25^\circ\text{C}$	-	0.07	-	$\text{V}/^\circ\text{C}$
$I_{\text{DS}}^{\text{SS}}$	Zero Gate Voltage Drain Current	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	1	μA
		$V_{DS} = 80 \text{ V}, T_C = 150^\circ\text{C}$	-	-	500	
I_{GSS}	Gate to Body Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	± 100	nA

On Characteristics

$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu\text{A}$	2.0	-	4.0	V
$R_{DS(\text{on})}$	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 96 \text{ A}$	-	6.5	8.5	$\text{m}\Omega$
g_{FS}	Forward Transconductance	$V_{DS} = 10 \text{ V}, I_D = 96 \text{ A}$	-	76	-	S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	2025	2695	pF
C_{oss}	Output Capacitance		-	468	620	pF
C_{rss}	Reverse Transfer Capacitance		-	20	-	pF
$C_{\text{oss(er)}}$	Engry Related Output Capacitance	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V}$	-	752	-	pF
$Q_{\text{g(tot)}}$	Total Gate Charge at 10V		-	31	40	nC
Q_{gs}	Gate to Source Gate Charge	$V_{GS} = 10 \text{ V}, V_{DS} = 50 \text{ V}, I_D = 96 \text{ A}$	-	9.7	-	nC
Q_{gs2}	Gate Charge Threshold to Plateau		-	5.0	-	nC
Q_{gd}	Gate to Drain "Miller" Charge		(Note 4)	7.5	-	nC
ESR	Equivalent Series Resistance (G-S)	$f = 1 \text{ MHz}$	-	0.97	-	Ω

Switching Characteristics

$t_{\text{d(on)}}$	Turn-On Delay Time	$V_{DD} = 50 \text{ V}, I_D = 96 \text{ A}, V_{GS} = 10 \text{ V}, R_G = 4.7 \Omega$	-	18	46	ns
t_r	Turn-On Rise Time		-	22	54	ns
$t_{\text{d(off)}}$	Turn-Off Delay Time		-	29	68	ns
t_f	Turn-Off Fall Time		(Note 4)	8	26	ns

Drain-Source Diode Characteristics

I_S	Maximum Continuous Drain to Source Diode Forward Current	-	-	40	A
I_{SM}	Maximum Pulsed Drain to Source Diode Forward Current	-	-	160	A
V_{SD}	Drain to Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{SD} = 96 \text{ A}$	-	-	1.3
t_{rr}	Reverse Recovery Time	$V_{DD} = 50 \text{ V}, V_{GS} = 0 \text{ V}, I_{SD} = 96 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	59	-
Q_{rr}	Reverse Recovery Charge		-	80	-

Notes:

1. Repetitive rating: pulse-width limited by maximum junction temperature.
2. $L = 3 \text{ mH}, I_{AS} = 13.4 \text{ A}, R_G = 25 \Omega$, starting $T_J = 25^\circ\text{C}$.
3. $I_{SD} \leq 40 \text{ A}, dI/dt \leq 200 \text{ A}/\mu\text{s}, V_{DD} \leq \text{BV}_{\text{DSS}}$, starting $T_J = 25^\circ\text{C}$.
4. Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

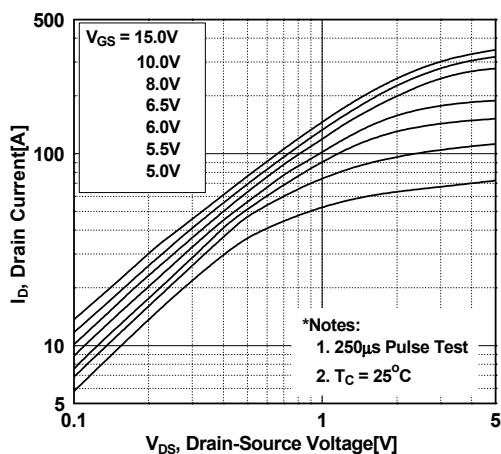


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

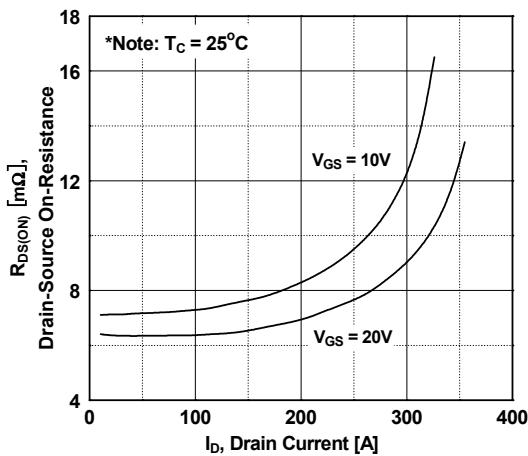


Figure 5. Capacitance Characteristics

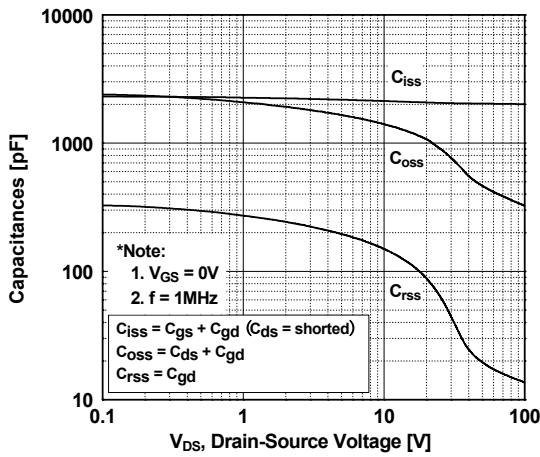


Figure 2. Transfer Characteristics

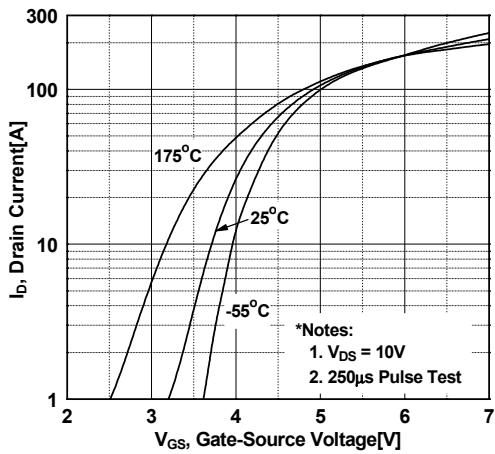


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

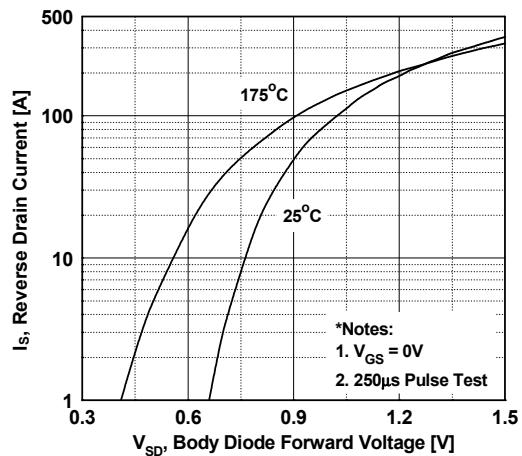
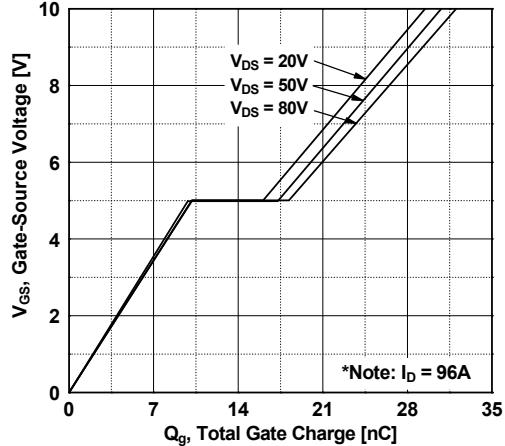


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

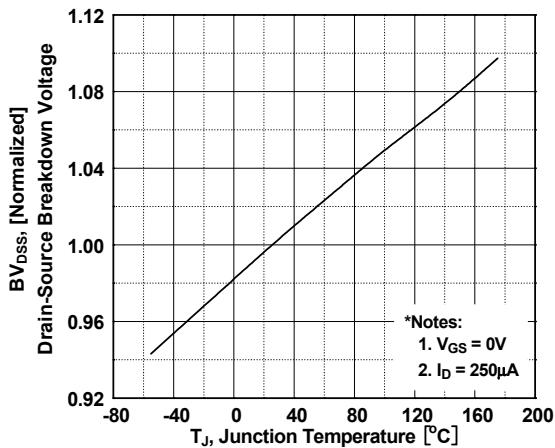


Figure 8. On-Resistance Variation vs. Temperature

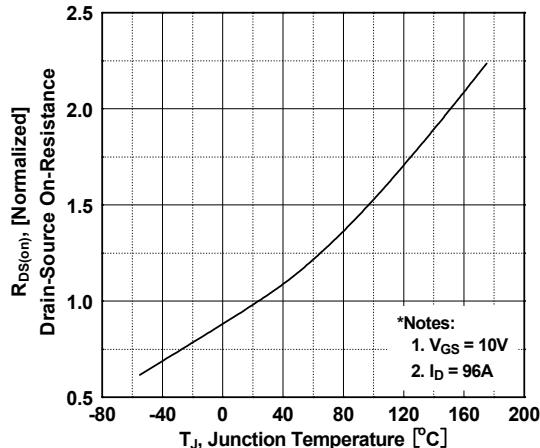


Figure 9. Maximum Safe Operating Area

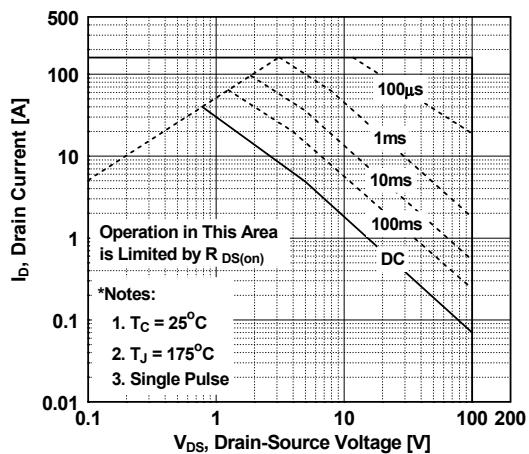


Figure 10. Maximum Drain Current vs. Case Temperature

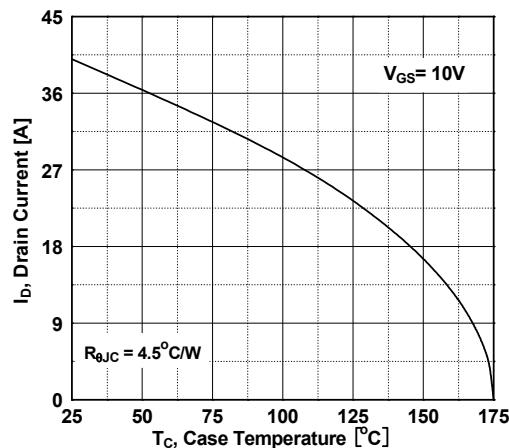


Figure 11. Eoss vs. Drain to Source Voltage

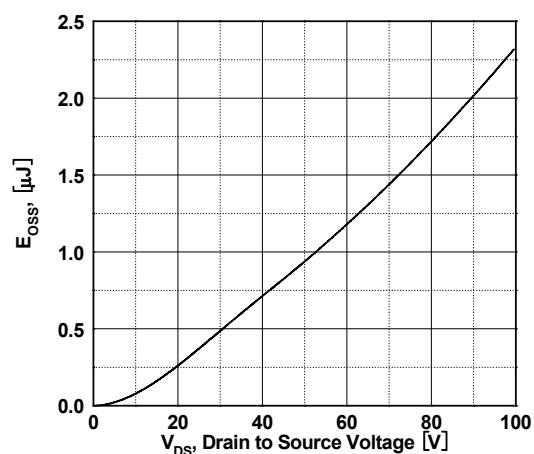
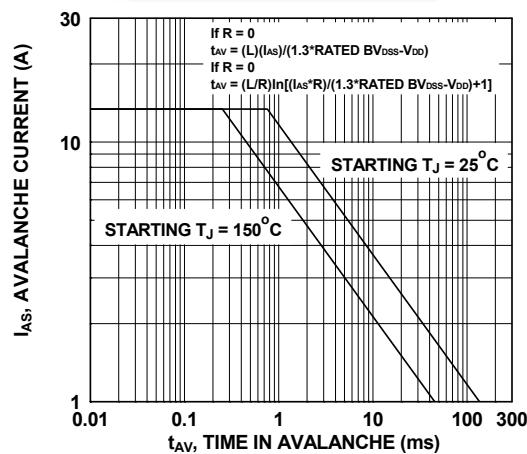
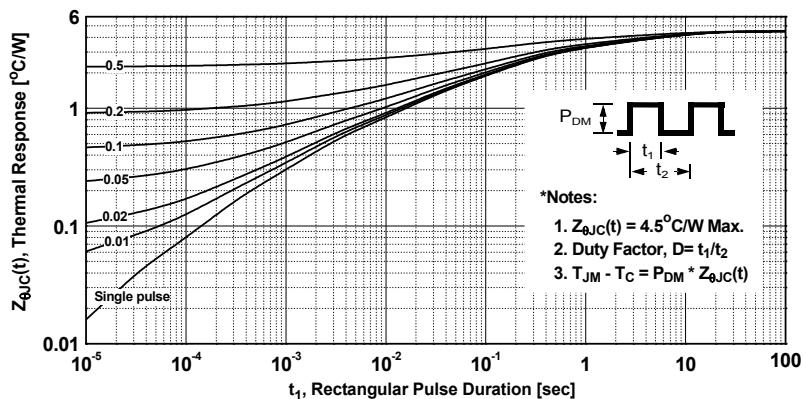


Figure 12. Unclamped Inductive Switching Capability



Typical Performance Characteristics (Continued)

Figure 13. Transient Thermal Response Curve



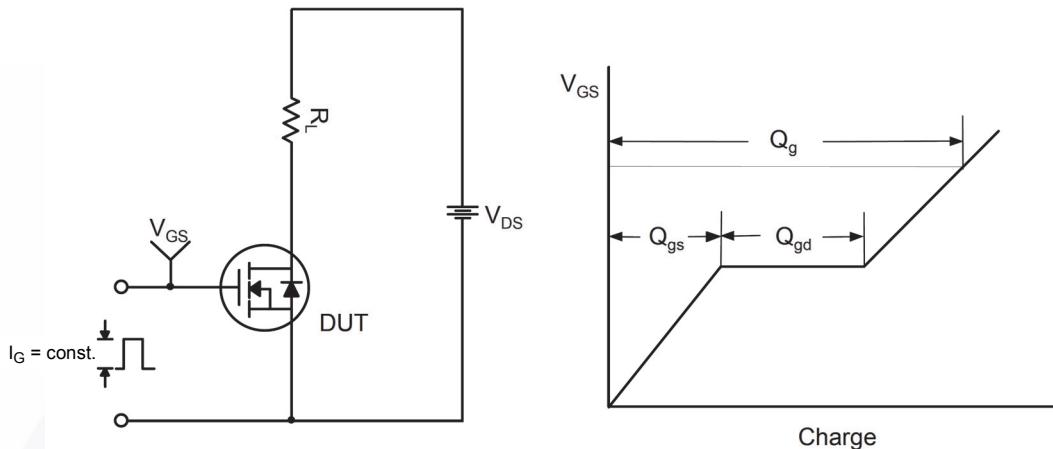


Figure 14. Gate Charge Test Circuit & Waveform

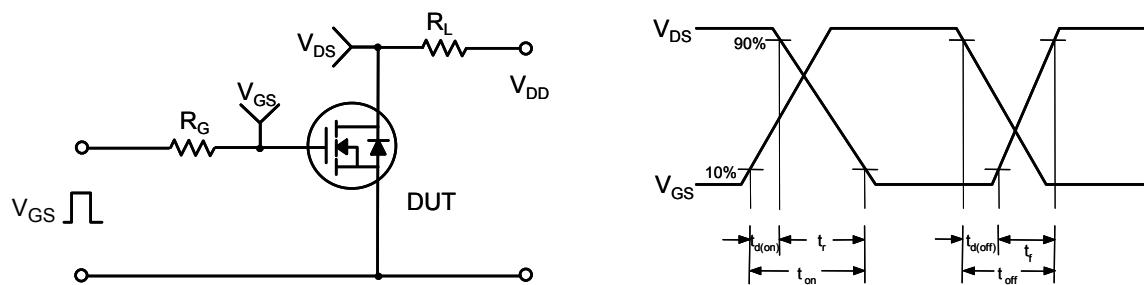


Figure 15. Resistive Switching Test Circuit & Waveforms

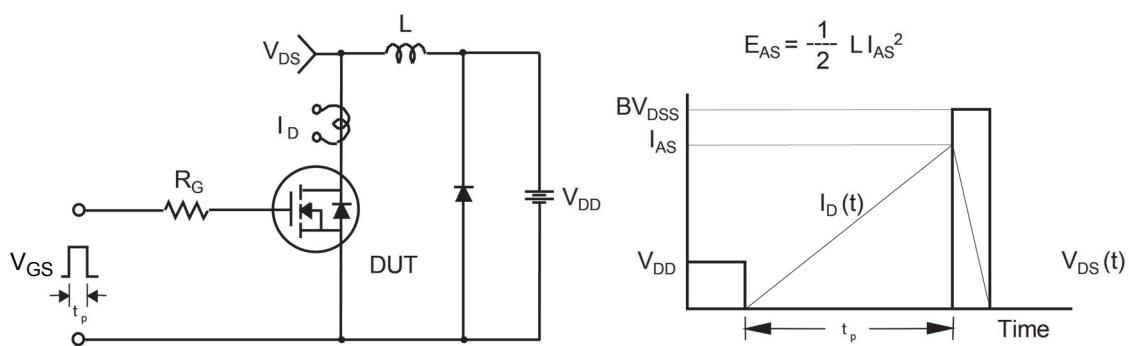


Figure 16. Unclamped Inductive Switching Test Circuit & Waveforms

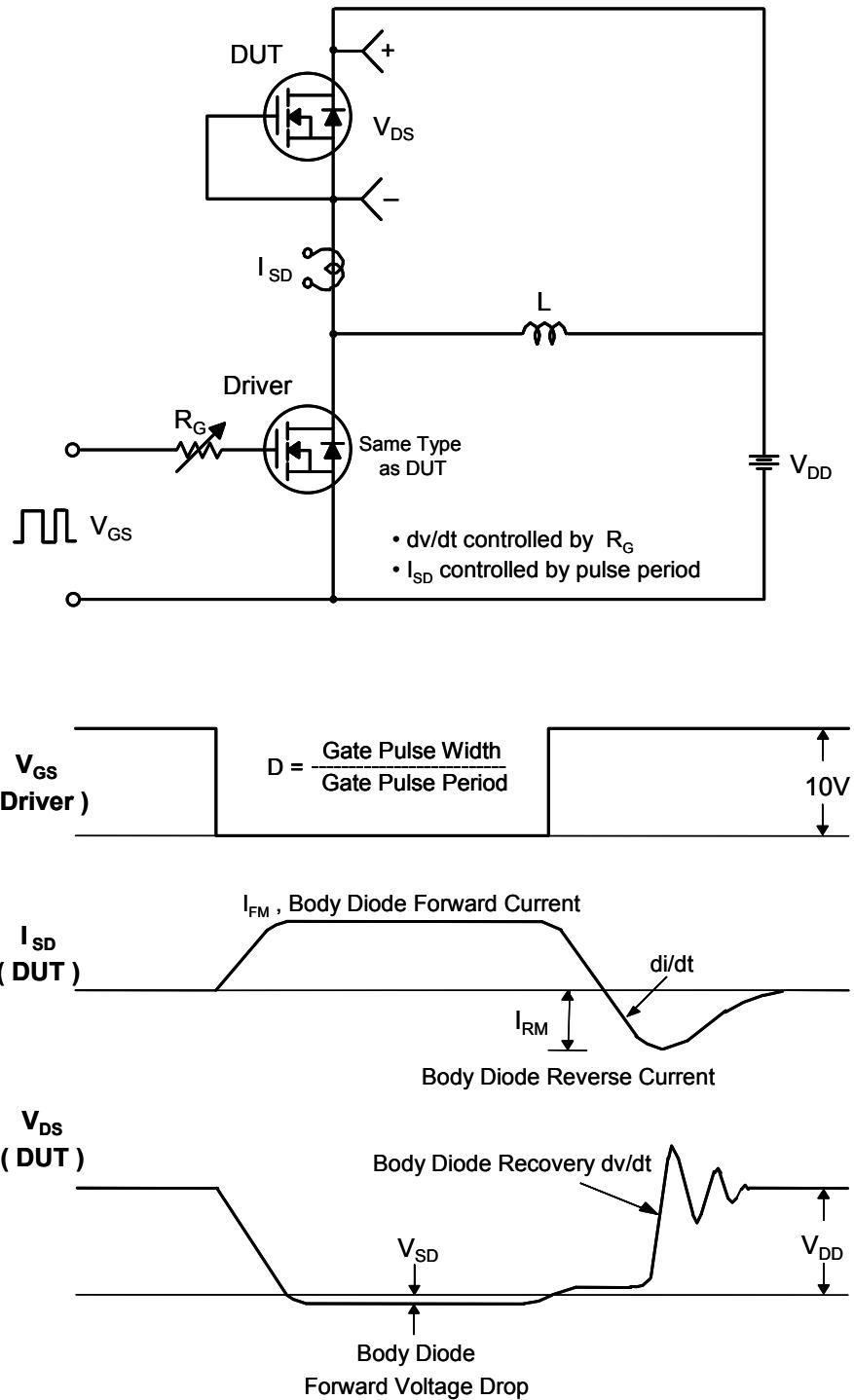


Figure 17. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

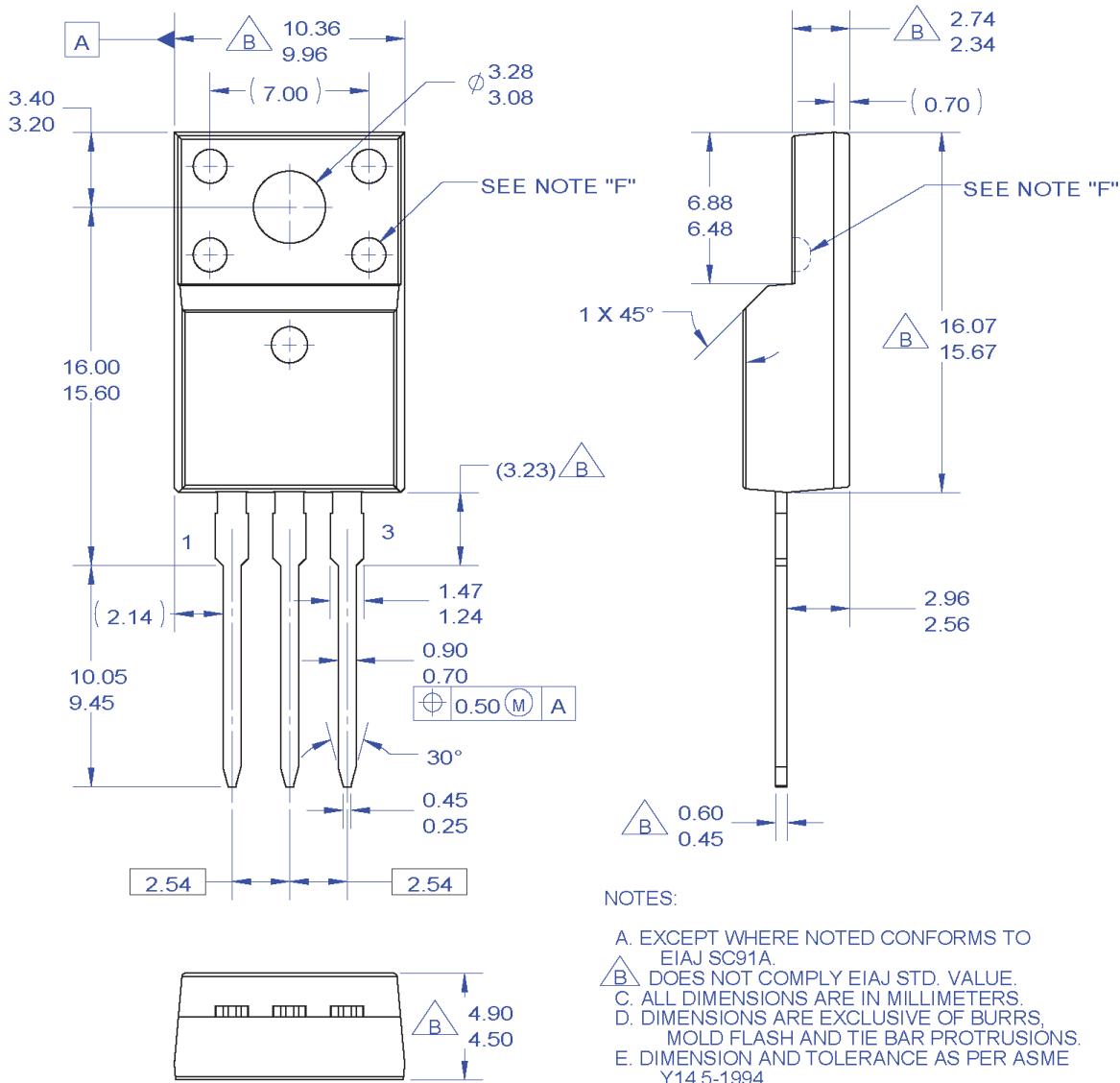


Figure 18. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead

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